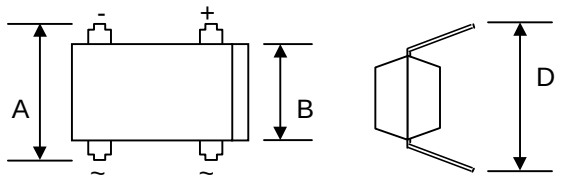
DF150 – DF1510

1.5A GLASS PASSIVATED BRIDGE RECTIFIER

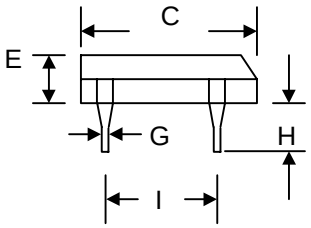
Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Surge Current Capability
- Designed for Surface Mount Application
- Plastic Material – UL Recognition Flammability Classification 94V-O



Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Case
- Weight: 0.38 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



*Low profile models (E = 2.20~2.50mm) are available. Please consult factory.

DIL		
Dim	**Min**	**Max**
A	7.40	7.90
B	6.20	6.50
C	8.13	8.51
D	7.60	8.90
E*	3.20	3.40
G	0.41	0.51
H	3.90	4.20
I	5.0	5.20
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	DF150	DF151	DF152	DF154	DF156	DF158	DF1510	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current @T_A = 40°C	I_O	1.5							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50							A
Forward Voltage per element @I_F = 1.5A	V_{FM}	1.1							V
Peak Reverse Current @T_A = 25°C At Rated DC Blocking Voltage @T_A = 125°C	I_{RM}	10 500							μA
Typical Junction Capacitance per element (Note 1)	C_j	25							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	40							K/W
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150							°C

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
2. Thermal resistance junction to ambient mounted on PC board with 13mm^2 copper pad.

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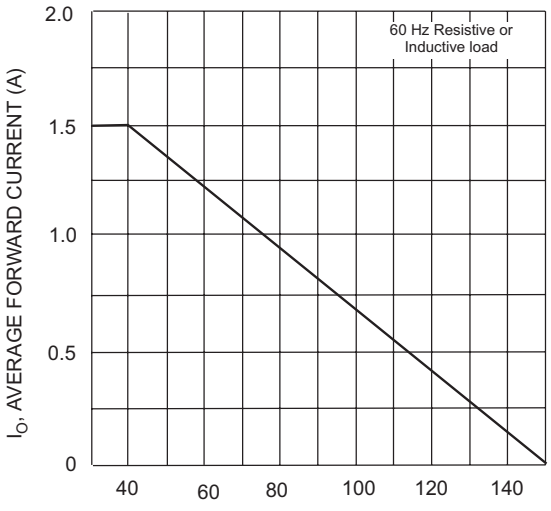
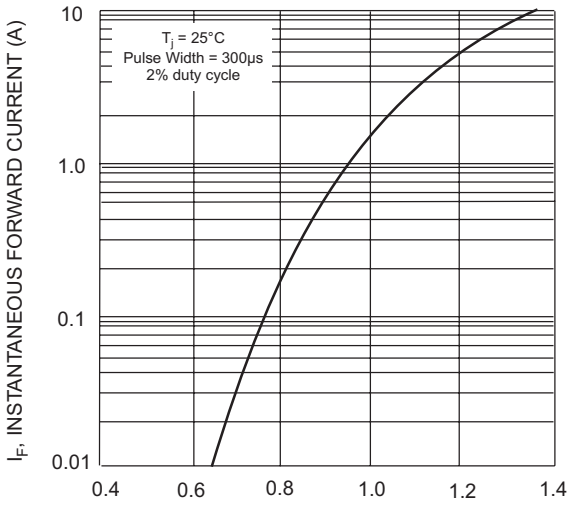
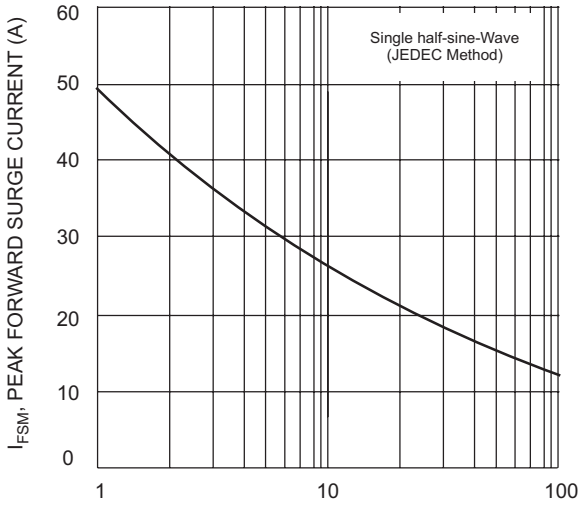


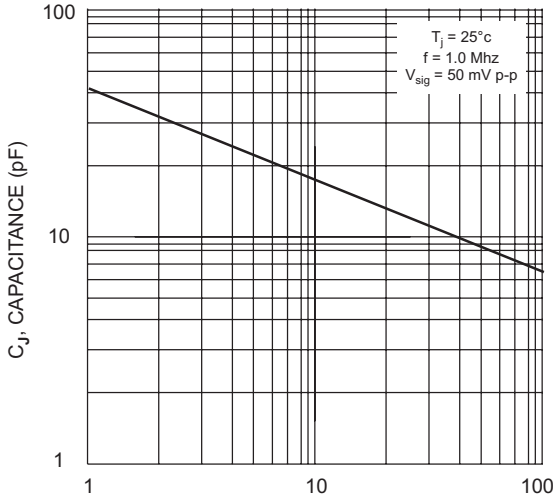
T_A, AMBIENT TEMPERATURE (°C)
Fig. 1 Output Current Derating Curve



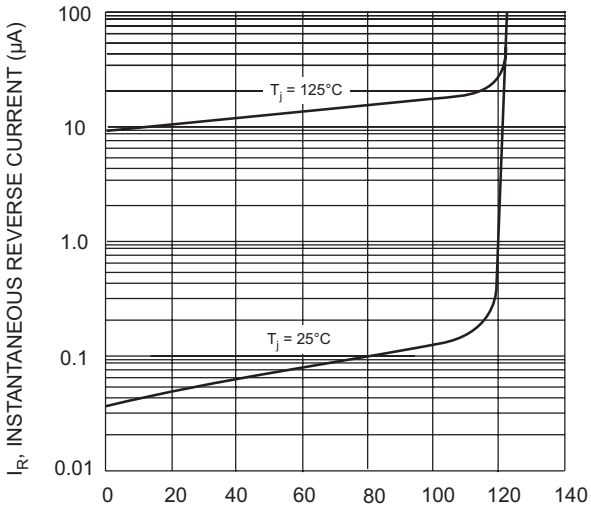
V_F, INSTANTANEOUS FORWARD VOLTAGE (V)
Fig. 2 Typ Forward Characteristics (per element)



NUMBER OF CYCLES AT 60 Hz
Fig. 3 Max Non-Repetitive Peak Forward Surge Current



V_R, REVERSE VOLTAGE (V)
Fig. 4 Typ Junction Capacitance (per element)



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)
Fig. 5 Typ Reverse Characteristics (per element)

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ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
DF150	DIL Bridge	50 Units/Tube
DF151	DIL Bridge	50 Units/Tube
DF152	DIL Bridge	50 Units/Tube
DF154	DIL Bridge	50 Units/Tube
DF156	DIL Bridge	50 Units/Tube
DF158	DIL Bridge	50 Units/Tube
DF1510	DIL Bridge	50 Units/Tube

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

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